NSN 5961-01-389-0258

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-389-0258 **Inclosure Material:** Glass **End Application:** Pacer dawn **Internal Configuration:** Field effect-dual gate **Mounting Method: Terminal Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 drain to source voltage and 30.0 drain to gate voltage **Special Features:** Esd **Terminal Type And Quantity:** 14 tab w/wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: